

# Cheng-Liang Huang

## List of Publications by Citations

**Source:** <https://exaly.com/author-pdf/7037537/cheng-liang-huang-publications-by-citations.pdf>

**Version:** 2024-04-27

This document has been generated based on the publications and citations recorded by exaly.com. For the latest version of this publication list, visit the link given above.

The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

216  
papers

3,644  
citations

34  
h-index

47  
g-index

225  
ext. papers

3,983  
ext. citations

3.7  
avg, IF

5.59  
L-index

#	Paper	IF	Citations
216	Improved high q value of MgTiO <sub>3</sub> -CaTiO <sub>3</sub> microwave dielectric ceramics at low sintering temperature. <i>Materials Research Bulletin</i> , <b>2001</b> , 36, 2741-2750	5.1	141
215	Dielectric Properties of Low Loss (1-x)(Mg <sub>0.95</sub> Zn <sub>0.05</sub> )TiO <sub>3</sub> -xSrTiO <sub>3</sub> Ceramic System at Microwave Frequency. <i>Journal of the American Ceramic Society</i> , <b>2007</b> , 90, 858-862	3.8	82
214	Liquid phase sintering of (Zr,Sn)TiO <sub>4</sub> microwave dielectric ceramics. <i>Materials Research Bulletin</i> , <b>2000</b> , 35, 1881-1888	5.1	77
213	Characterization of Extremely Low Loss Dielectrics (Mg <sub>0.95</sub> Zn <sub>0.05</sub> )TiO <sub>3</sub> at Microwave Frequency. <i>Japanese Journal of Applied Physics</i> , <b>2007</b> , 46, 283-285	1.4	75
212	Microwave Dielectric Properties of Sintered Alumina Using Nano-Scaled Powders of $\alpha$ -Alumina and TiO <sub>2</sub> . <i>Journal of the American Ceramic Society</i> , <b>2007</b> , 90, 1487-1493	3.8	72
211	Liquid phase sintering of MgTiO <sub>3</sub> -CaTiO <sub>3</sub> microwave dielectric ceramics. <i>Materials Chemistry and Physics</i> , <b>2003</b> , 78, 111-115	4.4	68
210	Low-Loss Microwave Dielectrics in the (Mg <sub>1-x</sub> Zn <sub>x</sub> ) <sub>2</sub> TiO <sub>4</sub> Ceramics. <i>Journal of the American Ceramic Society</i> , <b>2008</b> , 91, 3428-3430	3.8	67
209	High-Q Microwave Dielectrics in the (Mg <sub>1-x</sub> Cox) <sub>2</sub> TiO <sub>4</sub> Ceramics. <i>Journal of the American Ceramic Society</i> , <b>2009</b> , 92, 379-383	3.8	65
208	Sintering behavior and microwave dielectric properties of nano alpha-alumina. <i>Materials Letters</i> , <b>2005</b> , 59, 3746-3749	3.3	65
207	Low temperature sintering and microwave dielectric properties of Ba <sub>2</sub> Ti <sub>9</sub> O <sub>20</sub> ceramics using glass additions. <i>Materials Research Bulletin</i> , <b>2000</b> , 35, 2445-2456	5.1	65
206	Dielectric properties of (1-y)Ca <sub>1-x</sub> La <sub>2x/3</sub> TiO <sub>3-y</sub> (Li,Nd) <sub>1/2</sub> TiO <sub>3</sub> ceramic system at microwave frequency. <i>Materials Research Bulletin</i> , <b>2001</b> , 36, 547-556	5.1	60
205	Effect of ZnO additive on sintering behavior and microwave dielectric properties of 0.95MgTiO <sub>3</sub> 0.05CaTiO <sub>3</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2008</b> , 450, 359-363	5.7	58
204	High-Q dielectrics using ZnO-modified Li <sub>2</sub> TiO <sub>3</sub> ceramics for microwave applications. <i>Journal of the European Ceramic Society</i> , <b>2012</b> , 32, 3287-3295	6	53
203	High-Q microwave dielectrics in low-temperature sintered (Zn <sub>1-x</sub> Nix) <sub>3</sub> Nb <sub>2</sub> O <sub>8</sub> ceramics. <i>Journal of the European Ceramic Society</i> , <b>2014</b> , 34, 277-284	6	51
202	Low-loss microwave dielectrics using rock salt oxide Li <sub>2</sub> MgTiO <sub>4</sub> . <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, L308-L310	5.7	51
201	Low-Loss Microwave Dielectric Ceramics Using (Mg <sub>1-x</sub> Mnx) <sub>2</sub> TiO <sub>4</sub> (x=0.020.1) Solid Solution. <i>Journal of the American Ceramic Society</i> , <b>2009</b> , 92, 675-678	3.8	51
200	Dielectric characteristics of the (1-x)Mg <sub>2</sub> TiO <sub>4</sub> -xSrTiO <sub>3</sub> ceramic system at microwave frequencies. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 471, L9-L12	5.7	51

199	Effects of additives on microstructures and microwave dielectric properties of (Zr, Sn)TiO <sub>4</sub> ceramics. <i>Materials Chemistry and Physics</i> , <b>2001</b> , 71, 17-22	4.4	51
198	Dielectric Characteristics of Nd(Zn <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> Ceramics at Microwave Frequencies. <i>Journal of the American Ceramic Society</i> , <b>2006</b> , 89, 1465-1470	3.8	50
197	Low temperature sintering and microwave dielectric properties of SmAlO <sub>3</sub> ceramics. <i>Materials Research Bulletin</i> , <b>2002</b> , 37, 563-574	5.1	50
196	Improved high Q value of CaTiO <sub>3</sub> (Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> solid solution with near zero temperature coefficient of resonant frequency. <i>Materials Research Bulletin</i> , <b>2001</b> , 36, 1645-1652	5.1	49
195	Effect of B <sub>2</sub> O <sub>3</sub> Additives on Sintering and Microwave Dielectric Behaviors of CuO-Doped ZnNb <sub>2</sub> O <sub>6</sub> Ceramics. <i>Japanese Journal of Applied Physics</i> , <b>2002</b> , 41, 758-762	1.4	46
194	Low Dielectric Loss Ceramics in the ZnAl <sub>2</sub> O <sub>4</sub> -TiO <sub>2</sub> System as a $\mu$ Compensator. <i>Journal of the American Ceramic Society</i> , <b>2009</b> , 92, 119-124	3.8	44
193	High Q Microwave Dielectric Ceramics in the Li <sub>2</sub> (Zn <sub>1-x</sub> Ax)Ti <sub>3</sub> O <sub>8</sub> (A = Mg, Co; x = 0.02-0.1) System. <i>Journal of the American Ceramic Society</i> , <b>2011</b> , 94, 4146-4149	3.8	42
192	Improved high-Q microwave dielectric resonator using CuO-doped MgNb <sub>2</sub> O <sub>6</sub> ceramics. <i>Materials Research Bulletin</i> , <b>2003</b> , 38, 1091-1099	5.1	42
191	Low-Dielectric Loss Characteristics of Nd(Co <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> Ceramics at Microwave Frequencies. <i>Journal of the American Ceramic Society</i> , <b>2007</b> , 90, 1619-1622	3.8	40
190	Effect of CuO additive on sintering and microwave dielectric behavior of LaAlO <sub>3</sub> ceramics. <i>Materials Research Bulletin</i> , <b>2001</b> , 36, 1939-1947	5.1	39
189	Dielectric properties of (1-x)(Mg <sub>0.95</sub> Co <sub>0.05</sub> )TiO <sub>3</sub> -xCaTiO <sub>3</sub> ceramic system at microwave frequency. <i>Materials Research Bulletin</i> , <b>2002</b> , 37, 2483-2490	5.1	38
188	Low-Temperature Sintering and Microwave Dielectric Properties of (1-x)MgTiO <sub>3</sub> -xCaTiO <sub>3</sub> Ceramics Using Bismuth Addition. <i>Japanese Journal of Applied Physics</i> , <b>2002</b> , 41, 707-711	1.4	38
187	Low-Loss Microwave Dielectrics in the Spinel-Structured (Mg <sub>1-x</sub> Nix)Al <sub>2</sub> O <sub>4</sub> Solid Solutions. <i>Journal of the American Ceramic Society</i> , <b>2010</b> , 93, 1999	3.8	35
186	Effect of B <sub>2</sub> O <sub>3</sub> additives on sintering and microwave dielectric behaviors of 0.66Ca(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> -0.34CaTiO <sub>3</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2008</b> , 461, 440-446	5.7	35
185	Phase Relation and Microwave Dielectric Properties of (Zn <sub>1-x</sub> Cox)Ta <sub>2</sub> O <sub>6</sub> System. <i>Journal of the American Ceramic Society</i> , <b>2010</b> , 93, 1248	3.8	34
184	Phase Evolution and Dielectric Properties of (Mg <sub>0.95</sub> M <sub>0.05</sub> +x)Ti <sub>2</sub> O <sub>5</sub> (M <sub>2</sub> = Co, Ni, and Zn) Ceramics at Microwave Frequencies. <i>Journal of the American Ceramic Society</i> , <b>2009</b> , 92, 384-388	3.8	34
183	Effect of V <sub>2</sub> O <sub>5</sub> and CuO additives on sintering behavior and microwave dielectric properties of BiNbO <sub>4</sub> ceramics. <i>Journal of Materials Science</i> , <b>2000</b> , 35, 5443-5447	4.3	34
182	Influence of V <sub>2</sub> O <sub>5</sub> additions to NdAlO <sub>3</sub> ceramics on sintering temperature and microwave dielectric properties. <i>Journal of the European Ceramic Society</i> , <b>2003</b> , 23, 167-173	6	33

181	Low-Loss Microwave Dielectrics Using $\text{Mg}_2(\text{Ti}_{1-x}\text{Sn}_x)\text{O}_4$ ( $x=0.01\text{--}0.09$ ) Solid Solution. <i>Journal of the American Ceramic Society</i> , <b>2009</b> , 92, 2237-2241	3.8	30
180	A new low-loss microwave dielectric using $(\text{Ca}_{0.8}\text{Sr}_{0.2})\text{TiO}_3$ -doped $\text{MgTiO}_3$ ceramics. <i>Materials Letters</i> , <b>2010</b> , 64, 2585-2588	3.3	30
179	New dielectric material system of $(\text{Mg}_{0.95}\text{Zn}_{0.05})\text{TiO}_3\text{--}(\text{Ca}_{0.61}\text{Nd}_{0.26}\text{TiO}_3)$ at microwave frequency. <i>Journal of Alloys and Compounds</i> , <b>2008</b> , 453, 337-340	5.7	30
178	Characterization and dielectric behavior of CuO-doped $\text{ZnTa}_2\text{O}_6$ ceramics at microwave frequency. <i>Materials Research Bulletin</i> , <b>2004</b> , 39, 1701-1708	5.1	30
177	Dielectric properties of copper oxide doped $0.95\text{Ba}(\text{Zn}_{1/3}\text{Ta}_{2/3})\text{O}_3\text{--}0.05\text{BaZrO}_3$ ceramics at microwave frequency. <i>Materials Chemistry and Physics</i> , <b>2006</b> , 97, 256-260	4.4	28
176	Microwave dielectric properties of $x\text{Nd}(\text{Zn}_{1/2}\text{Ti}_{1/2})\text{O}_3\text{--}(1-x)\text{CaTiO}_3$ ceramics. <i>Materials Letters</i> , <b>2007</b> , 61, 4054-4057	3.3	27
175	High-Dielectric-Constant and Low-Loss Microwave Dielectric in the $(1-x)\text{Nd}(\text{Zn}_{1/2}\text{Ti}_{1/2})\text{O}_3\text{--}x\text{SrTiO}_3$ System with a Zero Temperature Coefficient of Resonant Frequency. <i>Journal of the American Ceramic Society</i> , <b>2008</b> , 91, 2201-2204	3.8	27
174	Dielectric Properties of $\text{CaTiO}_3\text{--}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ Ceramic System at Microwave Frequency. <i>Japanese Journal of Applied Physics</i> , <b>2000</b> , 39, 6608-6611	1.4	26
173	Characterization and dielectric behavior of $\text{V}_2\text{O}_5$ -doped $\text{MgTiO}_3\text{--}(\text{CaTiO}_3)$ ceramic system at microwave frequency. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , <b>2007</b> , 145, 91-96	3.1	25
172	Microwave Dielectric Properties of $(\text{Mg}_{1-x}\text{Ni}_x)_2\text{TiO}_4$ ( $x=0.02\text{--}0.1$ ) Ceramics. <i>International Journal of Applied Ceramic Technology</i> , <b>2010</b> , 7, E163-E169	2	24
171	Dielectric properties of $\text{B}_2\text{O}_3$ -doped $(1-x)\text{LaAlO}_3\text{--}x\text{SrTiO}_3$ ceramic system at microwave frequency. <i>Materials Research Bulletin</i> , <b>2002</b> , 37, 1941-1948	5.1	24
170	Synthesis, Crystal Structure, and Microwave Dielectric Properties of $(\text{Mg}_{1-x}\text{Co}_x)\text{Ta}_2\text{O}_6$ Solid Solutions. <i>Journal of the American Ceramic Society</i> , <b>2010</b> , 93, 470-473	3.8	23
169	Improved high Q value of $(1-x)\text{Ca}(\text{Mg}_{1/3}\text{Ta}_{2/3})\text{O}_3\text{--}x\text{Ca}_{0.8}\text{Sm}_{0.4/3}\text{TiO}_3$ solid solution with zero temperature coefficient of resonant frequency. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 494, 205-209	5.7	22
168	Influence of $\text{V}_2\text{O}_5$ additions to $0.8(\text{Mg}_{0.95}\text{Zn}_{0.05})\text{TiO}_3\text{--}0.2\text{Ca}_{0.61}\text{Nd}_{0.26}\text{TiO}_3$ ceramics on sintering behavior and microwave dielectric properties. <i>Journal of Alloys and Compounds</i> , <b>2008</b> , 454, 454-459	5.7	21
167	Dielectric characteristics of $\text{La}(\text{Co}_{1/2}\text{Ti}_{1/2})\text{O}_3$ ceramics at microwave frequencies. <i>Materials Letters</i> , <b>2004</b> , 58, 3732-3736	3.3	21
166	Ab Initio-Aided Sensitizer Design for $\text{Mn}^{4+}$ -Activated $\text{Mg}_2\text{TiO}_4$ as an Ultrabright Fluoride-Free Red-Emitting Phosphor. <i>Chemistry of Materials</i> , <b>2018</b> , 30, 1769-1775	9.6	20
165	Characterization and dielectric behavior of a new dielectric ceramics $\text{Ca}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3\text{--}(\text{Ca}_{0.8}\text{Sr}_{0.2})\text{TiO}_3$ at microwave frequencies. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 484, 494-497	5.7	20
164	Dielectric characteristics and sintering behavior of $\text{Mg}_2\text{TiO}_4\text{--}(\text{Ca}_{0.8}\text{Sr}_{0.2})\text{TiO}_3$ ceramic system at microwave frequency. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 487, 420-424	5.7	20

163	Influence of ZnO additions to 0.8(Mg <sub>0.95</sub> Co <sub>0.05</sub> )TiO <sub>3</sub> 0.2Ca <sub>0.6</sub> La <sub>0.8</sub> /3TiO <sub>3</sub> ceramics on sintering behavior and microwave dielectric properties. <i>Materials Letters</i> , <b>2006</b> , 60, 3591-3595	3-3	20
162	Microwave characteristics of Sm(Co <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> dielectric resonators. <i>Materials Letters</i> , <b>2004</b> , 58, 2829-2833	3-3	20
161	Dielectric properties of high-Q (Mg <sub>1-x</sub> Zn <sub>x</sub> ) <sub>1.8</sub> Ti <sub>1.1</sub> O <sub>4</sub> ceramics at microwave frequency. <i>Journal of the European Ceramic Society</i> , <b>2012</b> , 32, 2365-2371	6	19
160	Microwave dielectric properties and microstructures of MgTa <sub>2</sub> O <sub>6</sub> ceramics with CuO addition. <i>Materials Chemistry and Physics</i> , <b>2005</b> , 90, 373-377	4-4	19
159	Structural characteristics and microwave dielectric properties of low-firing Ba(Co <sub>1-x</sub> Mg <sub>x</sub> ) <sub>2</sub> (VO <sub>4</sub> ) <sub>2</sub> (x = 0.05) ceramics. <i>Journal of Alloys and Compounds</i> , <b>2016</b> , 686, 608-615	5-7	18
158	Low-loss microwave dielectric ceramics in the (Co <sub>1-x</sub> Zn <sub>x</sub> )TiO <sub>3</sub> (x = 0.0-1) system. <i>Journal of Alloys and Compounds</i> , <b>2012</b> , 515, 8-11	5-7	18
157	A new low-loss dielectric using CaTiO <sub>3</sub> -modified (Mg <sub>0.95</sub> Mn <sub>0.05</sub> )TiO <sub>3</sub> ceramics for microwave applications. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 499, 48-52	5-7	18
156	Dielectric properties of a new ceramic system (1-x)Mg <sub>4</sub> Nb <sub>2</sub> O <sub>9</sub> -xCaTiO <sub>3</sub> at microwave frequency. <i>Materials Research Bulletin</i> , <b>2009</b> , 44, 1111-1115	5-1	18
155	Effect of CuO addition to Nd(Zn <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> ceramics on sintering behavior and microwave dielectric properties. <i>Materials Letters</i> , <b>2009</b> , 63, 103-105	3-3	18
154	Microwave dielectric properties and sintering behaviors of (Mg <sub>0.95</sub> Ni <sub>0.05</sub> )TiO <sub>3</sub> -TaTiO <sub>3</sub> ceramic system. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 472, 451-455	5-7	18
153	Dielectric properties and mixture behavior of Mg <sub>4</sub> Nb <sub>2</sub> O <sub>9</sub> -BrTiO <sub>3</sub> ceramic system at microwave frequency. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 478, 554-558	5-7	18
152	Microwave dielectric properties and microstructures of La(Mg <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> with CuO-doped. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , <b>2006</b> , 128, 98-102	3-1	18
151	Effect of CaTiO <sub>3</sub> addition on microwave dielectric properties of Mg <sub>2</sub> (Ti <sub>0.95</sub> Sn <sub>0.05</sub> )O <sub>4</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, 4247-4251	5-7	17
150	Characterization and dielectric behavior of V <sub>2</sub> O <sub>5</sub> -doped 0.9Mg <sub>0.95</sub> Co <sub>0.05</sub> TiO <sub>3</sub> 0.1Ca <sub>0.6</sub> La <sub>0.8</sub> /3TiO <sub>3</sub> ceramic system at microwave frequency. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 489, 170-174	5-7	17
149	High-Q microwave dielectric in the (1-x)MgTiO <sub>3</sub> -xCa <sub>0.6</sub> La <sub>0.8</sub> /3TiO <sub>3</sub> ceramic system with a near-zero temperature coefficient of the resonant frequency. <i>Materials Letters</i> , <b>2008</b> , 62, 3205-3208	3-3	17
148	Properties of reactively radio frequency-magnetron sputtered (Zr,Sn)TiO <sub>4</sub> dielectric films. <i>Journal of Applied Physics</i> , <b>2004</b> , 96, 1186-1191	2-5	17
147	Highly c-axis oriented thin AlN films deposited on gold seed layer for FBAR devices. <i>Journal of Vacuum Science &amp; Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , <b>2005</b> , 23, 1474		17
146	Shifting $\beta$ value of BiNbO <sub>4</sub> ceramics by BiTaO <sub>4</sub> addition. <i>Journal of Materials Science Letters</i> , <b>2000</b> , 19, 375-376		17

- 145 Improvements in the sintering behavior and microwave dielectric properties of Mg<sub>4</sub>Nb<sub>2</sub>O<sub>9</sub> by adding Fe<sub>2</sub>O<sub>3</sub>. *Journal of Alloys and Compounds*, **2010**, 495, L5-L7 5-7 16
- 144 Dielectric properties and applications of low loss (1-x)(Mg<sub>0.95</sub>Co<sub>0.05</sub>)TiO<sub>3</sub>-xCa<sub>0.8</sub>Sm<sub>0.4</sub>/3TiO<sub>3</sub> ceramic system at microwave frequency. *Journal of Alloys and Compounds*, **2009**, 468, 516-521 5-7 16
- 143 Microwave dielectric properties and sintering behavior of nano-scaled (x)Al<sub>2</sub>O<sub>3</sub> ceramics. *Materials Research Bulletin*, **2008**, 43, 1463-1471 5-1 16
- 142 Microwave dielectric properties and mixture behavior of (Mg<sub>0.95</sub>Co<sub>0.05</sub>)TiO<sub>3</sub>-xLa<sub>0.6</sub>La<sub>0.8</sub>/3TiO<sub>3</sub> ceramic system. *Journal of Alloys and Compounds*, **2008**, 461, 521-526 5-7 16
- 141 Microwave properties of B<sub>2</sub>O<sub>3</sub>-doped Nd(Mg<sub>1/2</sub>Ti<sub>1/2</sub>)O<sub>3</sub>-xTaTiO<sub>3</sub> dielectric resonators at microwave frequency. *Materials Letters*, **2006**, 60, 198-202 3-3 16
- 140 Microwave dielectric properties and microstructures of CuO- and ZnO-doped LaAlO<sub>3</sub> ceramics. *Materials Research Bulletin*, **2002**, 37, 449-457 5-1 16
- 139 Microwave dielectric properties and microstructure of Ba<sub>2</sub>-xSm<sub>4+2x</sub>/3Ti<sub>8+y</sub>O<sub>24+2y</sub> ceramics. *Materials Science & Engineering A: Structural Materials: Properties, Microstructure and Processing*, **2003**, 345, 106-112 5-3 16
- 138 Characterization and microwave dielectric properties of Mg<sub>2</sub>YVO<sub>6</sub> ceramic. *Journal of Alloys and Compounds*, **2015**, 641, 93-98 5-7 15
- 137 Microwave Dielectric Characteristics of (Mg<sub>0.95</sub>M<sub>0.05</sub>)Ta<sub>2</sub>O<sub>6</sub> (M=Ni, Zn, Mn) Ceramic Series. *Materials Letters*, **2012**, 76, 28-31 3-3 15
- 136 Microwave Dielectric Properties of (Mg<sub>0.95</sub>Ni<sub>0.05</sub>)TiO<sub>3</sub>-BrTiO<sub>3</sub> Ceramics with a Near-Zero Temperature Coefficient of Resonant Frequency. *International Journal of Applied Ceramic Technology*, **2010**, 7, 207-216 2 15
- 135 High Dielectric Constant and Low-Loss Microwave Dielectric Ceramics Using (Zn<sub>0.95</sub>M<sub>2+0.05</sub>)Ta<sub>2</sub>O<sub>6</sub> (M<sub>2+</sub>=Mn, Mg, and Ni) Solid Solutions. *Journal of the American Ceramic Society*, **2010**, 93, 3299-3304 3-8 15
- 134 Characterization and dielectric behavior of B<sub>2</sub>O<sub>3</sub>-doped 0.9Mg<sub>0.95</sub>Co<sub>0.05</sub>TiO<sub>3</sub>-0.1Ca<sub>0.6</sub>La<sub>0.8</sub>/3TiO<sub>3</sub> ceramic system at microwave frequency. *Journal of Alloys and Compounds*, **2010**, 504, 228-232 5-7 15
- 133 Microwave dielectric properties of (1-x)(Mg<sub>0.95</sub>Zn<sub>0.05</sub>)TiO<sub>3</sub>-x(Na<sub>0.5</sub>La<sub>0.5</sub>)TiO<sub>3</sub> ceramic system. *Journal of Alloys and Compounds*, **2009**, 472, 497-501 5-7 15
- 132 A Wideband Cross Monopole Antenna. *IEEE Transactions on Antennas and Propagation*, **2009**, 57, 2464-2468 4-8 15
- 131 Microwave dielectric properties of a new ceramic system (1-x)(Mg<sub>0.95</sub>Zn<sub>0.05</sub>)TiO<sub>3</sub>-xCaTiO<sub>3</sub> at microwave frequencies. *Materials Letters*, **2008**, 62, 3773-3775 3-3 15
- 130 Influence of B<sub>2</sub>O<sub>3</sub> additions to 0.8(Mg<sub>0.95</sub>Zn<sub>0.05</sub>)TiO<sub>3</sub>-0.2Ca<sub>0.6</sub>Nd<sub>0.26</sub>TiO<sub>3</sub> ceramics on sintering behavior and microwave dielectric properties. *Journal of Alloys and Compounds*, **2008**, 460, 675-679 5-7 15
- 129 Structures and dielectric properties of a new dielectric material system xMgTiO<sub>3</sub>-(1-x)MgTa<sub>2</sub>O<sub>6</sub> at microwave frequency. *Journal of Alloys and Compounds*, **2007**, 431, 326-330 5-7 15
- 128 Microwave dielectric properties of Ba<sub>2</sub>-xSm<sub>4+2/3x</sub>Ti<sub>9</sub>O<sub>26</sub> ceramics with zero temperature coefficient. *Materials Science & Engineering A: Structural Materials: Properties, Microstructure and Processing*, **2002**, 334, 250-256 5-3 15

127	Improved high Q value of 0.5LaAlO <sub>3</sub> -0.5SrTiO <sub>3</sub> microwave dielectric ceramics at low sintering temperature. <i>Materials Research Bulletin</i> , <b>2001</b> , 36, 2677-2687	5.1	15
126	Influence of Mg substitutions for Zn on the phase relation and microwave dielectric properties of (Zn <sub>1-x</sub> Mg <sub>x</sub> ) <sub>3</sub> Nb <sub>2</sub> O <sub>8</sub> (x = 0.02-0.0) system. <i>Journal of Alloys and Compounds</i> , <b>2013</b> , 581, 257-262	5.7	14
125	Dielectric properties of magnesium oxide at microwave frequency. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 504, 284-287	5.7	14
124	Crystal structure and dielectric properties of xCa(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> (1-x)(Ca <sub>0.61</sub> Nd <sub>0.26</sub> )TiO <sub>3</sub> at the microwave frequency. <i>Materials Research Bulletin</i> , <b>2015</b> , 63, 1-5	5.1	13
123	Textured Magnesium Titanate as Gate Oxide for GaN-Based Metal-Oxide-Semiconductor Capacitor. <i>Journal of the American Ceramic Society</i> , <b>2011</b> , 94, 1005-1007	3.8	13
122	The effect of Ca <sub>0.61</sub> Nd <sub>0.26</sub> TiO <sub>3</sub> addition on the microwave dielectric properties of (Mg <sub>0.95</sub> Ni <sub>0.05</sub> )TiO <sub>3</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 475, 391-395	5.7	13
121	Low-loss microwave dielectrics using SrTiO <sub>3</sub> -modified (Mg <sub>0.95</sub> Co <sub>0.05</sub> ) <sub>2</sub> TiO <sub>4</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 485, 706-710	5.7	13
120	New dielectric material system of x(Mg <sub>0.95</sub> Zn <sub>0.05</sub> Ti)O <sub>3</sub> (1-x)Ca <sub>0.8</sub> Sm <sub>0.4</sub> /3TiO <sub>3</sub> at microwave frequency. <i>Materials Letters</i> , <b>2008</b> , 62, 2454-2457	3.3	13
119	A wideband planar inverted-F dielectric resonator antenna for RFID system applications. <i>Microwave and Optical Technology Letters</i> , <b>2006</b> , 48, 1302-1305	1.2	13
118	Dielectric properties of 0.95Ba(Zn <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> 0.05BaZrO <sub>3</sub> ceramics at microwave frequency. <i>Materials Letters</i> , <b>2003</b> , 57, 3602-3605	3.3	13
117	High-Q microwave dielectrics in the (Mg <sub>1-x</sub> Zn <sub>x</sub> )Al <sub>2</sub> O <sub>4</sub> (x = 0-0.1) system. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, L150-L152	5.7	12
116	The effect of non-stoichiometry on the microstructure and microwave dielectric properties of the Mg <sub>1-x</sub> TiO <sub>3-x</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, 9702-9707	5.7	12
115	New dielectric material system of Nd(Mg <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> CaTiO <sub>3</sub> with V <sub>2</sub> O <sub>5</sub> addition for microwave applications. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 489, 719-721	5.7	12
114	Reduced Dielectric Loss of Modified ZnNb <sub>2</sub> O <sub>6</sub> Ceramics by Substituting Nb <sup>5+</sup> with Ta <sup>5+</sup> . <i>Journal of the American Ceramic Society</i> , <b>2009</b> , 92, 1845-1848	3.8	12
113	Microwave dielectric properties of (1-x)CaO-xBaO-Li <sub>2</sub> O-(1-y)Sm <sub>2</sub> O <sub>3</sub> -yNd <sub>2</sub> O <sub>3</sub> -TiO <sub>2</sub> ceramics system. <i>Journal of Materials Science</i> , <b>2000</b> , 35, 4901-4905	4.3	12
112	Sol-gel derived TiNb <sub>2</sub> O <sub>7</sub> dielectric thin films for transparent electronic applications. <i>Journal of the American Ceramic Society</i> , <b>2018</b> , 101, 674-682	3.8	12
111	Microwave dielectric properties of low-loss (Zn <sub>1-x</sub> Co <sub>x</sub> ) <sub>3</sub> Nb <sub>2</sub> O <sub>8</sub> ceramics for LTCC applications. <i>Journal of Alloys and Compounds</i> , <b>2015</b> , 620, 18-23	5.7	11
110	Low-loss microwave dielectrics using (Mg <sub>1-x</sub> Zn <sub>x</sub> ) <sub>4</sub> Nb <sub>2</sub> O <sub>9</sub> (x=0.02-0.08) solid solutions. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, 2269-2272	5.7	11

109	Low-Loss Microwave Dielectrics in the $(\text{Mg}_{1-x}\text{Co}_x)_{1.8}\text{Ti}_{1.1}\text{O}_4$ ( $x=0.03\text{--}1.00$ ) Solid Solutions. <i>Journal of the American Ceramic Society</i> , <b>2011</b> , 94, 2963-2967	3.8	11
108	Microwave dielectric characteristics of $(\text{Mg}_{0.95}\text{Ni}_{0.05})\text{TiO}_3\text{--}(\text{Ca}_{0.8}\text{Sm}_{0.4}/3)\text{TiO}_3$ ceramic system. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 477, 720-725	5.7	11
107	Microwave dielectric properties of $(\text{Mg}_{0.95}\text{Co}_{0.05})\text{TiO}_3\text{--}(\text{Na}_{0.5}\text{Nd}_{0.5})\text{TiO}_3$ ceramic system. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 478, 842-846	5.7	11
106	Dielectric properties of a low-loss $(1-x)(\text{Mg}_{0.95}\text{Zn}_{0.05})_2\text{TiO}_4\text{--}x\text{SrTiO}_3$ ceramic system at microwave frequencies. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 480, 794-797	5.7	11
105	Characteristics of High-Q Microwave Dielectric Ceramics $\text{Nd}(\text{Co}_{1/2}\text{Ti}_{1/2})\text{O}_3$ With CuO Addition. <i>Journal of the American Ceramic Society</i> , <b>2007</b> , 90, 2409-2414	3.8	11
104	New Dielectric Material System of $\text{La}(\text{Mg}_{1/2}\text{Ti}_{1/2})\text{O}_3\text{--}x\text{TaTiO}_3$ at Microwave Frequencies. <i>Japanese Journal of Applied Physics</i> , <b>2005</b> , 44, 3147-3150	1.4	11
103	The synthesis and photoluminescence enhancement of sensitizer-doped $\text{Li}_2\text{MgTi}_3\text{O}_8\text{:Mn}^{4+}$ red phosphor. <i>Journal of Alloys and Compounds</i> , <b>2019</b> , 787, 440-447	5.7	10
102	Strong Near-Infrared Photoluminescence Emission of (003)-Oriented $\text{MgTiO}_3$ Thin Films. <i>Journal of the American Ceramic Society</i> , <b>2013</b> , 96, 2065-2068	3.8	10
101	The effect of deposition temperature and chamber pressure on the electrical and physical properties of the $\text{MgTiO}_3$ thin films. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 480, 897-902	5.7	10
100	Phase development and dielectric properties of $\text{BaAl}_2\text{Si}_2\text{O}_8$ -based low temperature co-fire ceramic material. <i>Journal of the Ceramic Society of Japan</i> , <b>2008</b> , 116, 935-940	1	10
99	New compact microstrip stacked slotted resonators bandpass filter with transmission zeros using high-permittivity ceramics substrate. <i>Microwave and Optical Technology Letters</i> , <b>2008</b> , 50, 1377-1379	1.2	10
98	New dielectric materials of $x\text{SrTiO}_3\text{--}(1-x)\text{Ca}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ ceramic system at microwave frequency. <i>Materials Letters</i> , <b>2006</b> , 60, 1280-1283	3.3	10
97	Low loss and temperature stable microwave dielectrics using $\text{Li}_2(\text{Mg}_{1-x}\text{A}_x)\text{Ti}_3\text{O}_8$ ( $\text{A}^{2+}=\text{Zn}, \text{Co}; x=0.02\text{--}0.1$ ) ceramics. <i>Journal of Alloys and Compounds</i> , <b>2014</b> , 607, 67-72	5.7	9
96	Low-firable high-K dielectric in the $\text{Zr}_x(\text{Zn}_{1/3}\text{Nb}_{2/3})_{1-x}\text{TiO}_4$ ceramic system. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, L293-L295	5.7	9
95	Structure, Dielectric Properties, and Applications of $\text{CaTiO}_3$ -Modified $\text{Ca}_4\text{MgNb}_2\text{TiO}_{12}$ Ceramics at Microwave Frequency. <i>Journal of the American Ceramic Society</i> , <b>2011</b> , 94, 1824-1828	3.8	9
94	Dielectric properties of $\text{B}_2\text{O}_3$ -doped $0.92(\text{Mg}_{0.95}\text{Co}_{0.05})_2\text{TiO}_4\text{--}0.08(\text{Ca}_{0.8}\text{Sr}_{0.2})\text{TiO}_3$ ceramics for microwave applications. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 505, 291-296	5.7	9
93	Dielectric properties of $\text{Mg}_{0.95}\text{Ni}_{0.05}\text{TiO}_3$ ceramic modified by $\text{Nd}_{0.5}\text{Na}_{0.5}\text{TiO}_3$ at microwave frequencies. <i>Current Applied Physics</i> , <b>2009</b> , 9, 1042-1045	2.6	9
92	New dielectric material system of $\text{Mg}_{0.95}\text{Co}_{0.05}\text{TiO}_3\text{--}x\text{Nd}_{0.975}\text{Ca}_{0.025}\text{TiO}_3$ at microwave frequencies. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 477, 712-715	5.7	9



91	Investigation of the microwave dielectric properties of Li <sub>2</sub> ZnTi <sub>5</sub> O <sub>12</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2016</b> , 678, 102-108	5.7	9
90	Thermal Reaction of Cristobalite in Nano-SiO <sub>2</sub> /Al <sub>2</sub> O <sub>3</sub> Powder Systems for Mullite Synthesis. <i>Journal of the American Ceramic Society</i> , <b>2014</b> , 97, 2431-2438	3.8	8
89	High-Q microwave dielectrics in the (Mg <sub>1-x</sub> Zn <sub>x</sub> ) <sub>4</sub> Ta <sub>2</sub> O <sub>9</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2014</b> , 590, 494-499	5.7	8
88	Intense Red Photoluminescence Emission of Sol-Gel-Derived Nanocrystalline Mg <sub>2</sub> TiO <sub>4</sub> Thin Films. <i>Journal of the American Ceramic Society</i> , <b>2014</b> , 97, 358-360	3.8	8
87	High-dielectric-constant and low-loss microwave dielectric in the Ca(Mg <sub>1/3</sub> Ta <sub>2/3</sub> )O <sub>3</sub> -(Ca <sub>0.8</sub> Sr <sub>0.2</sub> )TiO <sub>3</sub> solid solution system. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , <b>2010</b> , 167, 142-146	3.1	8
86	Improved microwave dielectric properties of B <sub>2</sub> O <sub>3</sub> -doped Nd(Co <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> ceramics with near zero temperature coefficient of resonant frequency. <i>Materials Research Bulletin</i> , <b>2007</b> , 42, 9-16	5.1	8
85	Compact 5.8-GHz bandpass filter using stepped-impedance dielectric resonators for ISM band wireless communication. <i>Microwave and Optical Technology Letters</i> , <b>2005</b> , 44, 421-423	1.2	8
84	Sol-Gel-Derived Amorphous-MgNb <sub>2</sub> O <sub>6</sub> Thin Films for Transparent Microelectronics. <i>Journal of the American Ceramic Society</i> , <b>2013</b> , 96, 3375-3378	3.8	7
83	High-dielectric-constant and low-loss microwave dielectric in the (1-x)La(Mg <sub>0.5</sub> Ti <sub>0.5</sub> )O <sub>3</sub> -(Ca <sub>0.8</sub> Sr <sub>0.2</sub> )TiO <sub>3</sub> solid solution system. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, L99-L102	5.7	7
82	A novel low-loss microwave dielectric using (Ca <sub>0.8</sub> Sr <sub>0.2</sub> )TiO <sub>3</sub> -modified (Mg <sub>0.95</sub> Co <sub>0.05</sub> ) <sub>2</sub> TiO <sub>4</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 496, L10-L13	5.7	7
81	Microwave dielectric properties of x(Mg <sub>0.7</sub> Zn <sub>0.3</sub> ) <sub>0.95</sub> Co <sub>0.05</sub> TiO <sub>3</sub> -(1-x)Ca <sub>0.8</sub> Sr <sub>0.2</sub> TiO <sub>3</sub> ceramics with a zero temperature coefficient of resonant frequency. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 503, 392-396	5.7	7
80	Microwave dielectric properties of (1-x)(Mg <sub>0.95</sub> Co <sub>0.05</sub> )TiO <sub>3</sub> -(Na <sub>0.5</sub> La <sub>0.5</sub> )TiO <sub>3</sub> ceramic system. <i>Current Applied Physics</i> , <b>2009</b> , 9, 1355-1359	2.6	7
79	High dielectric constant low loss in the (La <sub>1/2</sub> Na <sub>1/2</sub> )TiO <sub>3</sub> -(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> ceramic system at microwave frequency. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 468, L13-L16	5.7	7
78	Influence of ZnO additions to 0.96Mg <sub>0.95</sub> Co <sub>0.05</sub> TiO <sub>3</sub> -0.04SrTiO <sub>3</sub> ceramics on sintering behavior and microwave dielectric properties. <i>Journal of Alloys and Compounds</i> , <b>2009</b> , 469, 357-361	5.7	7
77	Microstrip-fed monopole dumbbell-shaped antenna for UWB application. <i>Microwave and Optical Technology Letters</i> , <b>2007</b> , 49, 1470-1473	1.2	7
76	Low firable 0.95MgTiO <sub>3</sub> -0.05CaTiO <sub>3</sub> microwave dielectrics. <i>Journal of Materials Science Letters</i> , <b>2002</b> , 21, 149-151		7
75	Microwave dielectric properties of B <sub>2</sub> O <sub>3</sub> doped LaAlO <sub>3</sub> ceramics at low sintering temperature. <i>Journal of Materials Science</i> , <b>2003</b> , 38, 3495-3500	4.3	7
74	Microwave Dielectric Properties of (1-x)(Mg <sub>0.95</sub> Ni <sub>0.05</sub> )TiO <sub>3</sub> -(Ca <sub>0.8</sub> Sr <sub>0.2</sub> )TiO <sub>3</sub> Ceramic System With Near-Zero Temperature Coefficient. <i>International Journal of Applied Ceramic Technology</i> , <b>2012</b> , 9, 447-453	2	6

73	MgTiO <sub>3</sub> (003) Thin Film Deposited on Sapphire (0001) by Sputtering. <i>Journal of the American Ceramic Society</i> , <b>2011</b> , 94, 363-366	3.8	6
72	Low-Temperature Sintering Microwave Dielectrics Using CuO-Doped Zn(Nb <sub>0.95</sub> Ta <sub>0.05</sub> ) <sub>2</sub> O <sub>6</sub> Ceramics. <i>Journal of the American Ceramic Society</i> , <b>2010</b> , 93, 2755-2759	3.8	6
71	A Novel Temperature-Compensated Microwave Dielectric (1-x)(Mg <sub>0.95</sub> Ni <sub>0.05</sub> )TiO <sub>3</sub> -xCa <sub>0.6</sub> La <sub>0.8/3</sub> TiO <sub>3</sub> Ceramics System. <i>International Journal of Applied Ceramic Technology</i> , <b>2009</b> , 6, 562-570	2	6
70	Dielectric properties of (1-x)(Mg <sub>0.95</sub> Zn <sub>0.05</sub> )TiO <sub>3</sub> -x(Na <sub>0.5</sub> Nd <sub>0.5</sub> )TiO <sub>3</sub> ceramic system at microwave frequencies. <i>Materials Letters</i> , <b>2008</b> , 62, 2516-2519	3.3	6
69	Using high permittivity ceramic substrates to design a bandpass filter with open stub. <i>Microwave and Optical Technology Letters</i> , <b>2007</b> , 49, 771-773	1.2	6
68	Multilayer ceramic bandpass filter at microwave frequency. <i>Microwave and Optical Technology Letters</i> , <b>2000</b> , 24, 258-260	1.2	6
67	Sintering behavior and microwave dielectric properties of ZnCuTiO <sub>4</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2015</b> , 638, 29-33	5.7	5
66	Temperature Compensating Microwave Dielectric Based on the (Mg <sub>0.95</sub> Ni <sub>0.05</sub> )TiO <sub>3</sub> (La <sub>0.5</sub> Na <sub>0.5</sub> )TiO <sub>3</sub> Ceramic System. <i>International Journal of Applied Ceramic Technology</i> , <b>2009</b> , 7, E64-E70	2	5
65	The effect of RF power and deposition temperature on the structure and electrical properties of Mg <sub>4</sub> Ta <sub>2</sub> O <sub>9</sub> thin films prepared by RF magnetron sputtering. <i>Journal of Crystal Growth</i> , <b>2009</b> , 311, 627-633 <sup>1.6</sup>	1.6	5
64	A new dielectric material system using (1-x)(Mg <sub>0.95</sub> Co <sub>0.05</sub> ) <sub>2</sub> TiO <sub>4</sub> -xCa <sub>0.8</sub> Sm <sub>0.4/3</sub> TiO <sub>3</sub> at microwave frequencies. <i>Materials Chemistry and Physics</i> , <b>2010</b> , 120, 217-220	4.4	5
63	Microwave dielectric properties of Mg <sub>1.8</sub> Ti <sub>1.1</sub> O <sub>4</sub> ceramics. <i>Materials Letters</i> , <b>2010</b> , 64, 885-887	3.3	5
62	Dual-band multilayer ceramic microwave bandpass filter for applications in wireless communication. <i>Microwave and Optical Technology Letters</i> , <b>2002</b> , 32, 327-329	1.2	5
61	Miniaturization of hairpin bandpass filters using high-permittivity substrate. <i>Microwave and Optical Technology Letters</i> , <b>2005</b> , 45, 222-225	1.2	5
60	Effect of Inner Electrode on Electrical Properties of (Zn,Mg)TiO <sub>3</sub> -Based Multilayer Ceramic Capacitor. <i>Japanese Journal of Applied Physics</i> , <b>2005</b> , 44, 8519-8524	1.4	5
59	High-Q Li <sub>2</sub> Mg <sub>2</sub> (MoO <sub>4</sub> ) <sub>3</sub> dielectrics for LTCC applications at microwave frequencies. <i>Journal of Asian Ceramic Societies</i> , <b>2020</b> , 8, 430-436	2.4	4
58	Dielectric properties of B <sub>2</sub> O <sub>3</sub> doped Sm(Co <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> ceramics at microwave frequency. <i>Journal of Materials Science</i> , <b>2007</b> , 42, 2393-2398	4.3	4
57	Miniaturization microstrip rectangular-ring bandpass filter using high permittivity substrate. <i>Microwave and Optical Technology Letters</i> , <b>2006</b> , 48, 540-543	1.2	4
56	Planar compact elliptic-function low-pass filter using high-permittivity ceramics substrate. <i>Microwave and Optical Technology Letters</i> , <b>2006</b> , 48, 1393-1398	1.2	4

55	Structural and Dielectric Properties of ZnO-Doped (Zr 0.8 Sn 0.2 )TiO <sub>4</sub> Films at Radio Frequency. <i>Integrated Ferroelectrics</i> , <b>2003</b> , 51, 127-136	0.8	4
54	Properties of ZnO-doped Zr <sub>0.8</sub> Sn <sub>0.2</sub> TiO <sub>4</sub> thin films by rf sputtering. <i>Journal of Vacuum Science &amp; Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , <b>2003</b> , 21, 670		4
53	Resistive Switching Property of Organic-Inorganic Tri-Cation Lead Iodide Perovskite Memory Device. <i>Nanomaterials</i> , <b>2020</b> , 10,	5.4	3
52	Dielectric properties and crystal structure of Mg <sub>4</sub> Ta <sub>2</sub> O <sub>9</sub> ceramics with Mg <sup>2+</sup> substituted by Co <sup>2+</sup> . <i>Journal of the Ceramic Society of Japan</i> , <b>2014</b> , 122, 556-560	1	3
51	New material properties and microstructure of xLa(Mg <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> (1-x)Ca <sub>0.6</sub> Sm <sub>0.8</sub> /3TiO <sub>3</sub> ceramics at microwave frequency. <i>Journal of the Ceramic Society of Japan</i> , <b>2014</b> , 122, 951-954	1	3
50	Resistive Switching Behaviors of Sol-Gel-Derived MgNb <sub>2</sub> O <sub>6</sub> Thin Films on ITO/glass Substrate. <i>Journal of the American Ceramic Society</i> , <b>2014</b> , 97, 3544-3548	3.8	3
49	Crystal structure and dielectric properties of La(Mg <sub>0.5</sub> Ti <sub>0.5</sub> )O <sub>3</sub> (1-x)Ca <sub>0.8</sub> Sm <sub>0.4</sub> /3TiO <sub>3</sub> solid solution system at microwave frequencies. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, 426-430	5.7	3
48	Low-loss microwave dielectrics in the Mg <sub>2</sub> (Ti <sub>0.95</sub> Sn <sub>0.05</sub> )O <sub>4</sub> (1-x)Ca <sub>0.8</sub> Sr <sub>0.2</sub> TiO <sub>3</sub> ceramic system. <i>Journal of Alloys and Compounds</i> , <b>2010</b> , 502, 324-328	5.7	3
47	Sintering Behavior and Dielectric Properties of ZnNb <sub>2</sub> O <sub>6</sub> /TiO <sub>2</sub> Ceramic System at Microwave Frequency. <i>Japanese Journal of Applied Physics</i> , <b>2009</b> , 48, 100203	1.4	3
46	Microwave dielectric properties of (1-x)(Mg <sub>0.95</sub> Co <sub>0.05</sub> )TiO <sub>3</sub> (1-x)Ca <sub>0.6</sub> La <sub>0.8</sub> /3TiO <sub>3</sub> ceramics with V <sub>2</sub> O <sub>5</sub> addition. <i>Solid-State Electronics</i> , <b>2006</b> , 50, 1349-1354	1.7	3
45	Microwave Dielectric Properties and Microstructures of 0.5La(Mg <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> (1-x)CaTiO <sub>3</sub> Ceramics with B <sub>2</sub> O <sub>3</sub> Addition. <i>Japanese Journal of Applied Physics</i> , <b>2005</b> , 44, 6706-6708	1.4	3
44	Pseudoelliptic bandpass filter realized using coupled stepped-impedance resonators with tapped I/O. <i>Microwave and Optical Technology Letters</i> , <b>2000</b> , 27, 105-109	1.2	3
43	A low-loss, low temperature sintering dielectric using Ba <sub>1-x</sub> Sr <sub>x</sub> Mg <sub>2</sub> (VO <sub>4</sub> ) <sub>2</sub> ceramics and its applications at microwave frequencies. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , <b>2021</b> , 268, 115114	3.1	3
42	Microwave dielectric properties of novel Na <sub>2</sub> Mg <sub>5-x</sub> Zn <sub>x</sub> (MoO <sub>4</sub> ) <sub>6</sub> (x = 0-0.09) ceramics for ULTCC applications. <i>Materials Research Bulletin</i> , <b>2021</b> , 141, 111355	5.1	3
41	Phase evolution and microwave dielectric properties of TiO <sub>2</sub> -modified (Mg <sub>0.95</sub> Co <sub>0.05</sub> ) <sub>2</sub> TiO <sub>4</sub> ceramics. <i>Journal of Alloys and Compounds</i> , <b>2011</b> , 509, 6273-6275	5.7	2
40	Quasi-elliptic function filters with a dual-passband response with high-permittivity ceramics substrate. <i>Microwave and Optical Technology Letters</i> , <b>2009</b> , 51, 245-248	1.2	2
39	Dielectric Properties of a New Ceramic System (Mg <sub>0.95</sub> Zn <sub>0.05</sub> ) <sub>2</sub> TiO <sub>4</sub> (1-x)TaTiO <sub>3</sub> at Microwave Frequencies. <i>Japanese Journal of Applied Physics</i> , <b>2009</b> , 48, 071402	1.4	2
38	Using high permittivity ceramic substrates to fabricate a miniaturized bandpass filter with capacitive load. <i>Microwave and Optical Technology Letters</i> , <b>2007</b> , 49, 1609-1613	1.2	2

37	Miniaturized hairpin resonator filters using dielectric ceramic substrates. <i>Microwave and Optical Technology Letters</i> , <b>2008</b> , 50, 620-624	1.2	2
36	Planar compact, broad-stopband elliptic-function lowpass filters using high-permittivity ceramic substrate. <i>Microwave and Optical Technology Letters</i> , <b>2006</b> , 48, 1432-1436	1.2	2
35	Resistive switching characteristics of sol-gel derived La <sub>2</sub> Zr <sub>2</sub> O <sub>7</sub> thin film for RRAM applications. <i>Journal of Alloys and Compounds</i> , <b>2022</b> , 899, 163294	5.7	2
34	Ultra-low temperature sintering and temperature stable microwave dielectrics of (Mg <sub>1-x</sub> Zn <sub>x</sub> )V <sub>2</sub> O <sub>6</sub> (x= 0.09) Ceramics. <i>Journal of Asian Ceramic Societies</i> , <b>2021</b> , 9, 106-112	2.4	2
33	Effect of a minute substitution on the structure and microwave dielectric properties of novel LiCoVO <sub>4</sub> ceramics for ULTCC applications. <i>Journal of Asian Ceramic Societies</i> , 1-11	2.4	2
32	The Effects of Annealing Atmosphere on the Electrical Properties of MgNb <sub>2</sub> O <sub>6</sub> /ITO Heterostructures. <i>Journal of the American Ceramic Society</i> , <b>2015</b> , 98, 580-586	3.8	1
31	Microwave dielectric properties of Li <sub>2</sub> M <sub>2</sub> (MoO <sub>4</sub> ) <sub>3</sub> (M=[Co, Ni]) for LTCC applications. <i>International Journal of Ceramic Engineering &amp; Science</i> , <b>2020</b> , 2, 130-139	2	1
30	Thin-Film Photoluminescent Properties and the Atomistic Model of Mg <sub>2</sub> TiO <sub>4</sub> as a Non-rare Earth Matrix Material for Red-Emitting Phosphor. <i>Journal of Electronic Materials</i> , <b>2016</b> , 45, 6214-6221	1.9	1
29	Ultra low loss microwave dielectric properties of Non-stoichiometry [(Mg <sub>0.7</sub> Zn <sub>0.3</sub> )] <sub>0.95</sub> Co <sub>0.05</sub> ] <sub>1-x</sub> (Ti <sub>1-x</sub> Sn <sub>x</sub> )O <sub>3</sub> + <sub>z</sub> Ceramics. <i>Journal of the Ceramic Society of Japan</i> , <b>2014</b> , 122, 762-767	1	1
28	Miniaturization of ring resonator bandpass filters using dielectric ceramic substrates. <i>Microwave and Optical Technology Letters</i> , <b>2013</b> , 55, 660-663	1.2	1
27	Ultrawideband planar microstrip-fed monopole antenna. <i>Microwave and Optical Technology Letters</i> , <b>2007</b> , 49, 183-185	1.2	1
26	Wideband microstrip-fed planar monopole antenna. <i>Microwave and Optical Technology Letters</i> , <b>2007</b> , 49, 1377-1383	1.2	1
25	Compact cross-coupled hairpin filter design using ceramic substrates. <i>Microwave and Optical Technology Letters</i> , <b>2008</b> , 50, 1795-1800	1.2	1
24	Simplified multilayer ceramic planar filter for wireless communication system. <i>Microwave and Optical Technology Letters</i> , <b>2000</b> , 25, 233-235	1.2	1
23	Planar SIR microwave bandpass filter using high-permittivity ceramics. <i>Microwave and Optical Technology Letters</i> , <b>2000</b> , 26, 410-413	1.2	1
22	Microwave dielectric properties and microstructures of BaO modified CaO-Li <sub>2</sub> O-Sm <sub>2</sub> O <sub>3</sub> -TiO <sub>2</sub> ceramics. <i>Journal of Materials Science Letters</i> , <b>2000</b> , 19, 2197-2199		1
21	Pseudoelliptic bandpass filter realization using attenuation pole resonator. <i>Microwave and Optical Technology Letters</i> , <b>1999</b> , 23, 275-277	1.2	1
20	Resistive switching characteristics of sol-gel derived ZrCeO <sub>x</sub> thin films for nonvolatile memory applications. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , <b>2022</b> , 277, 115605	3.1	1

19	Electrical properties and current conduction mechanisms of LaGdO <sub>3</sub> thin film by RF sputtering for RRAM applications. <i>Journal of Asian Ceramic Societies</i> , <b>2020</b> , 8, 948-956	2.4	1
18	Band-pass filters using high-permittivity ceramics substrate. <i>Microwave and Optical Technology Letters</i> , <b>2010</b> , 52, 2344-2347	1.2	0
17	A compact-size circularly polarized antenna using low-loss alumina substrates. <i>Microwave and Optical Technology Letters</i> , <b>2006</b> , 48, 2317-2320	1.2	0
16	Influence of intrinsic and extrinsic factors on microwave dielectric properties of (Sr <sub>1-x</sub> Mg <sub>x</sub> )V <sub>2</sub> O <sub>6</sub> (x=0.010.09) ceramics for ULTCC applications. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , <b>2021</b> , 273, 115438	3.1	0
15	Ultra-low temperature sintering and microwave dielectric properties of Mg-substituted SrCoV <sub>2</sub> O <sub>7</sub> ceramics. <i>Journal of Asian Ceramic Societies</i> , <b>2022</b> , 10, 188-195	2.4	0
14	Resistive switching properties of amorphous Sm <sub>2</sub> Ti <sub>2</sub> O <sub>7</sub> thin film prepared by RF sputtering for RRAM applications. <i>Journal of Alloys and Compounds</i> , <b>2022</b> , 910, 164960	5.7	0
13	Microwave Dielectric Properties of Sintered Alumina Using Nano-Scaled Powders of $\alpha$ -Alumina and TiO <sub>2</sub> <b>2014</b> , 149-155		
12	Sintering temperature dependences of (1 - $\alpha$ ); y)(Mg <sub>0.95</sub> Mn <sub>0.05</sub> ) <sub>2</sub> (Ti <sub>0.95</sub> Sn <sub>0.05</sub> ) <sub>4</sub> - y(Ca <sub>0.6</sub> La <sub>0.8/3</sub> )TiO <sub>3</sub> microwave dielectric ceramics with a zero temperature coefficient of resonant frequency. <i>Journal of the Ceramic Society of Japan</i> , <b>2015</b> , 123, 374-377	1	
11	Two-poles compact microstrip bandpass filter with sharp transition bands using high permittivity substrate. <i>Microwave and Optical Technology Letters</i> , <b>2012</b> , 54, 1683-1686	1.2	
10	End-coupled microstrip slow-wave resonator filters using high-permittivity ceramic substrate. <i>Microwave and Optical Technology Letters</i> , <b>2009</b> , 51, 1613-1615	1.2	
9	Microstrip ring resonator bandpass filters using ceramic substrate. <i>Microwave and Optical Technology Letters</i> , <b>2010</b> , 52, 218-220	1.2	
8	Planar monopole antenna with wideband operation. <i>Microwave and Optical Technology Letters</i> , <b>2007</b> , 49, 696-699	1.2	
7	A New Dielectric Material System of xLa(Mg <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> (1-x)CaTiO <sub>3</sub> at Microvave Frequency. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 783, 5111		
6	Micr owave Dielectric Properties of (1-x)CaTiO <sub>3</sub> -xNd(Mg <sub>1/2</sub> Ti <sub>1/2</sub> )O <sub>3</sub> Ceramics System. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 783, 5131		
5	Microwave characteristics of CuO-doped Ba(Ni <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> dielectric resonators. <i>Journal of Materials Science Letters</i> , <b>2003</b> , 22, 209-212		
4	Design and fabrication of a miniature monoblock bandpass filter using high-permittivity ceramic. <i>Microwave and Optical Technology Letters</i> , <b>2001</b> , 31, 95-97	1.2	
3	BSST high-permittivity coaxial-type direct-coupling microwave ceramic bandpass filters. <i>Microwave and Optical Technology Letters</i> , <b>2000</b> , 26, 258-260	1.2	
2	The effects of zinc substitution on the electrical properties of MgNb <sub>2</sub> O <sub>6</sub> thin films. <i>Journal of Asian Ceramic Societies</i> , <b>2021</b> , 9, 253-261	2.4	

- 1 The photoluminescence of single-phase warm white-light-emitting luminescence using CaSnO<sub>3</sub>: Ce<sup>3+</sup>/ Mn<sup>4+</sup>/ Dy<sup>3+</sup> phosphors. *Journal of Asian Ceramic Societies*,1-12 2.4